

## DECLARATION AND POWER OF ATTORNEY FOR U.S. PATENT APPLICATION

☐ Original ☐ Supplemental ☐ Substitute ☒ PCT ☐ DESIGN

As a below named inventor, I hereby declare that: my residence, post office address and citizenship are as stated below next to my name; that I verily believe that I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural inventors are named below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

Title: METHOD AND APPARATUS FOR GROWING HIGH QUALITY SINGLE CRYSTAL

of which is described and claimed in:

☐ the attached specification, or  
☐ the specification in application Serial No. \_\_\_\_\_, filed \_\_\_\_\_, and with amendments through \_\_\_\_\_, or  
☒ the specification in International Application No. PCT/JP00/03264, filed May 22, 2000, and as amended on \_\_\_\_\_ (if applicable).

I hereby state that I have reviewed and understand the content of the above-identified specification, including the claims, as amended by any amendment(s) referred to above.

I acknowledge my duty to disclose to the Patent and Trademark Office all information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations, §1.56.

I hereby claim priority benefits under Title 35, United States Code, §119 (and §172 if this application is for a Design) of any application(s) for patent or inventor's certificate listed below and have also identified below any application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

COUNTRY	APPLICATION NO.	DATE OF FILING	PRIORITY CLAIMED
Japan	1999-178815	May 22, 1999	YES

I hereby claim the benefit under Title 35, United States Code §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code §112, I acknowledge the duty to disclose information material to patentability as defined in Title 37, Code of Federal Regulations, §1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

APPLICATION SERIAL NO.	U.S. FILING DATE	STATUS: PATENTED, PENDING, ABANDONED

And I hereby appoint Michael R. Davis, Reg. No. 25,134; Matthew M. Jacob, Reg. No. 25,154; Warren M. Cheek, Jr., Reg. No. 33,367; Nils Pedersen, Reg. No. 33,145; Charles R. Watts, Reg. No. 33,142; and Michael S. Huppert, Reg. No. 40,268, who together constitute the firm of WENDEROTH, LIND & PONACK, L.L.P., as well as any other attorneys and agents associated with Customer No. 000513, to prosecute this application and to transact all business in the U.S. Patent and Trademark Office connected therewith.

I hereby authorize the U.S. attorneys and agents named herein to accept and follow instructions from NISHIZAWA & ASSOCIATES as to any action to be taken in the U.S. Patent and Trademark Office regarding this application without direct communication between the U.S. attorneys and myself. In the event of a change in the persons from whom instructions may be taken, the U.S. attorneys named herein will be so notified by me.

Direct Correspondence to Customer No:



000513

PATENT TRADEMARK OFFICE

Direct Telephone Calls to:

WENDEROTH, LIND & PONACK, L.L.P.  
 2033 "K" Street, N.W., Suite 300  
 Washington, D.C. 20006-1021

Phone: (202) 721-8200  
 Fax: (202) 721-8250

Full Name of First Inventor	FAMILY NAME SASAKI	FIRST GIVEN NAME Takatomo	SECOND GIVEN NAME
Residence & Citizenship	CITY Osaka,	STATE OR COUNTRY Japan	COUNTRY OF CITIZENSHIP Japan JPX
Post Office Address	ADDRESS 2-8, Yamada-nishi, Suita-shi, Osaka, Japan	CITY	STATE OR COUNTRY ZIP CODE
Full Name of Second Inventor	FAMILY NAME MORI	FIRST GIVEN NAME Yusuke	SECOND GIVEN NAME
Residence & Citizenship	CITY Osaka,	STATE OR COUNTRY Japan	COUNTRY OF CITIZENSHIP Japan JPX
Post Office Address	ADDRESS 16-9, Kisaichi 8-chome, Katano-shi, Osaka, Japan	CITY	STATE OR COUNTRY ZIP CODE
Full Name of Third Inventor	FAMILY NAME YOSHIMURA	FIRST GIVEN NAME Masashi	SECOND GIVEN NAME
Residence & Citizenship	CITY Hiroshima,	STATE OR COUNTRY Japan	COUNTRY OF CITIZENSHIP Japan JPX
Post Office Address	ADDRESS 2-10, Nobehiro-cho, Fukuyama-shi, Hiroshima, Japan	CITY	STATE OR COUNTRY ZIP CODE
Full Name of Fourth Inventor	FAMILY NAME	FIRST GIVEN NAME	SECOND GIVEN NAME
Residence & Citizenship	CITY	STATE OR COUNTRY	COUNTRY OF CITIZENSHIP
Post Office Address	ADDRESS	CITY	STATE OR COUNTRY ZIP CODE
Full Name of Fifth Inventor	FAMILY NAME	FIRST GIVEN NAME	SECOND GIVEN NAME
Residence & Citizenship	CITY	STATE OR COUNTRY	COUNTRY OF CITIZENSHIP
Post Office Address	ADDRESS	CITY	STATE OR COUNTRY ZIP CODE
Full Name of Sixth Inventor	FAMILY NAME	FIRST GIVEN NAME	SECOND GIVEN NAME
Residence & Citizenship	CITY	STATE OR COUNTRY	COUNTRY OF CITIZENSHIP
Post Office Address	ADDRESS	CITY	STATE OR COUNTRY ZIP CODE

I further declare that all statements made herein of my own knowledge are true, and that all statements on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

1st Inventor Takatomo Sasaki Date December 18, 2001  
Takatomo SASAKI  
2nd Inventor Yusuke Mori Date December 18, 2001  
Yusuke MORI  
3rd Inventor Masashi Yoshimura Date December 18, 2001  
Masashi YOSHIMURA  
4th Inventor \_\_\_\_\_ Date \_\_\_\_\_  
5th Inventor \_\_\_\_\_ Date \_\_\_\_\_  
6th Inventor \_\_\_\_\_ Date \_\_\_\_\_

The above application may be more particularly identified as follows:

U.S. Application Serial No. \_\_\_\_\_ Filing Date November 23, 2001

Applicant Reference Number 00-F-024US/UA Atty Docket No. 2001 1739A

Title of Invention METHOD AND APPARATUS FOR GROWING HIGH QUALITY SINGLE CRYSTAL